



XTR112 XTR114

4-20mA CURRENT TRANSMITTERS with Sensor Excitation and Linearization

FEATURES

- **LOW UNADJUSTED ERROR**
- PRECISION CURRENT SOURCES XTR112: Two 250μA XTR114: Two 100μA
- RTD OR BRIDGE EXCITATION
- LINEARIZATION
- TWO OR THREE-WIRE RTD OPERATION
- LOW OFFSET DRIFT: 0.4μV/°C
- LOW OUTPUT CURRENT NOISE: 30nAp-p
- HIGH PSR: 110dB minHIGH CMR: 86dB min
- WIDE SUPPLY RANGE: 7.5V TO 36V
- SO-14 SOIC PACKAGE

DESCRIPTION

The XTR112 and XTR114 are monolithic 4-20mA, two-wire current transmitters. They provide complete current excitation for high impedance platinum RTD temperature sensors and bridges, instrumentation amplifier, and current output circuitry on a single integrated circuit. The XTR112 has two 250µA current sources while the XTR114 has two 100µA sources for RTD excitation.

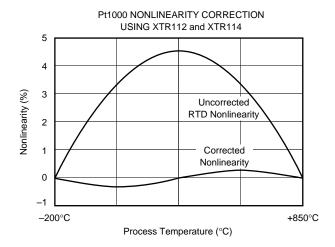
Versatile linearization circuitry provides a 2nd-order correction to the RTD, typically achieving a 40:1 improvement in linearity.

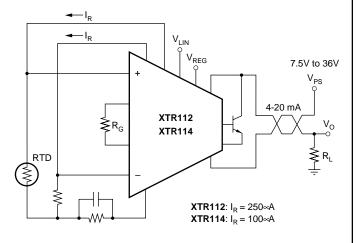
Instrumentation amplifier gain can be configured for a wide range of temperature or pressure measurements. Total unadjusted error of the complete current transmitter is low enough to permit use without adjustment in many applications. This includes zero output current drift, span drift and nonlinearity. The XTR112 and XTR114 operate on loop power supply voltages down to 7.5V.

Both are available in an SO-14 surface-mount package and are specified for the -40° C to $+85^{\circ}$ C industrial temperature range.

APPLICATIONS

- INDUSTRIAL PROCESS CONTROL
- FACTORY AUTOMATION
- SCADA REMOTE DATA ACQUISITION
- REMOTE TEMPERATURE AND PRESSURE TRANSDUCERS





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SPECIFICATIONS

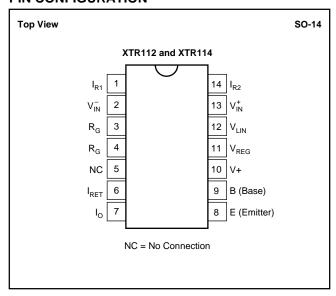
At T_A = +25°C, V+ = 24V, and TIP29C external transistor, unless otherwise noted.

			XTR112U XTR114U			XTR112UA XTR114UA	UNITS	
PARAMETER	CONDITIONS	MIN	TYP MAX		MIN	TYP		MAX
OUTPUT Output Current Equation Output Current, Specified Range		4	$I_0 = V_{IN} \bullet (40/R_G) + 4mA$, V_{IN} in Volts, R_G in Ω					
Over-Scale Limit		24	27	30	*	*	*	mA mA
Under-Scale Limit: XTR112	$I_{REG} = 0$	0.9	1.3	1.7	*	*	*	mA
XTR114		0.6	1	1.4	*	*	*	mA
ZERO OUTPUT(1) Initial Error vs Temperature vs Supply Voltage, V+ vs Common-Mode Voltage vs V _{REG} Output Current Noise: 0.1Hz to 10Hz	$V_{IN} = 0V, R_G = \infty$ $V_{IN} = 7.5V \text{ to } 36V$ $V_{CM} = 1.25V \text{ to } 3.5V^{(2)}$		4 ±5 ±0.07 0.04 0.02 0.3 0.03	±25 ±0.5 0.2		* * * * * *	±50 ±0.9 *	mA μA /°C μA/V μA/V μA/W μA/mA
SPAN			0.00					μιρρ
Span Equation (transconductance) Initial Error (3) vs Temperature(3) Nonlinearity: Ideal Input (4)	Full Scale $(V_{IN}) = 50 \text{mV}$ Full Scale $(V_{IN}) = 50 \text{mV}$		S = 40/R _G ±0.05 ±3 0.003	±0.2 ±25 0.01		* * * *	±0.4 * *	A/V % ppm/°C %
INPUT ⁽⁵⁾								
Offset Voltage vs Temperature vs Supply Voltage, V+ vs Common-Mode Voltage, RTI (CMRR)	$V_{CM} = 2V$ $V + = 7.5V \text{ to } 36V$ $V_{CM} = 1.25V \text{ to } 3.5V^{(2)}$		±50 ±0.4 ±0.3 ±10	±100 ±1.5 ±3 ±50		* * *	±250 ±3 * ±100	μV μV/°C μV/V μV/V
Common-Mode Input Range ⁽²⁾		1.25		3.5	*		*	V
Input Bias Current			5	25		*	50	nA
vs Temperature			20			*		pA/°C
Input Offset Current			±0.2	±3		*	±10	nA
vs Temperature			5			*		pA/°C
Impedance: Differential			0.1 1			*		GΩ pF
Common-Mode			5 10			*		GΩ pF
Noise: 0.1Hz to 10Hz	21/(0)		0.6			*		μVр-р
CURRENT SOURCES	$V_{O} = 2V^{(6)}$		050			.,		
Current: XTR112 XTR114			250 100			*		μA μA
Accuracy			±0.05	±0.2		*	±0.4	μA %
vs Temperature			±15	±35		*	±75	ppm/°C
vs Power Supply, V+	V+ = 7.5V to 36V		±10	±25		*	*	ppm/V
Matching			±0.02	±0.1		*	±0.2	%
vs Temperature			±3	±15		*	±30	ppm/°C
vs Power Supply, V+	V+ = 7.5V to 36V		1	10		*	*	ppm/V
Compliance Voltage, Positive		(V+) -3	(V+) -2.5		*	*		V
Negative ⁽²⁾		0	-0.2		*	*		V
Output Impedance: XTR112 XTR114			500 1.2			*		$M\Omega$ $G\Omega$
Noise: 0.1Hz to 10Hz: XTR112			0.001			*		μAp-p
XTR114			0.0004			*		μАр-р
V _{REG} ⁽²⁾			5.1			*		V
Accuracy			±0.02	±0.1		*	*	V
vs Temperature			±0.2			*		mV/°C
vs Supply Voltage, V+			1			*		mV/V
Output Current: XTR112			-1, +2.1			*		mA
XTR114			-1, +2.4			*		mA
Output Impedance		1	75			*		Ω
LINEARIZATION B. (internal)			1			J.		100
R _{LIN} (internal) Accuracy			±0.2	±0.5		*	±1	kΩ %
vs Temperature			±25	±0.5 ±100		*	*	ppm/°C
POWER SUPPLY				00		<u> </u>	<u> </u>	PP.11, 0
Specified Voltage			+24			*		V
Operating Voltage Range		+7.5	'-'	+36	*	"	*	v
TEMPERATURE RANGE		+ -		•	 	 		
Specification, T _{MIN} to T _{MAX}		-40		+85	*		*	∘c
Operating/Storage Range		-55		+125	*		*	°C
Thermal Resistance, θ_{JA}					1			1
SO-14 Surface-Mount			100			*		°C/W

^{*} Specification same as XTR112U, XTR114U.

NOTES: (1) Describes accuracy of the 4mA low-scale offset current. Does not include input amplifier effects. Can be trimmed to zero. (2) Voltage measured with respect to I_{RET} pin. (3) Does not include initial error or TCR of gain-setting resistor, R_G . (4) Increasing the full-scale input range improves nonlinearity. (5) Does not include Zero Output initial error. (6) Current source output voltage with respect to I_{RET} pin.

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATINGS(1)

Power Supply, V+ (referenced to I _O pin)	40V
Input Voltage, V _{IN} , V _{IN} (referenced to I _O pin)	0V to V+
Storage Temperature Range	55°C to +125°C
Lead Temperature (soldering, 10s)	+300°C
Output Current Limit	Continuous
Junction Temperature	+165°C

NOTE: (1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability.



This integrated circuit can be damaged by ESD. Burr-Brown recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

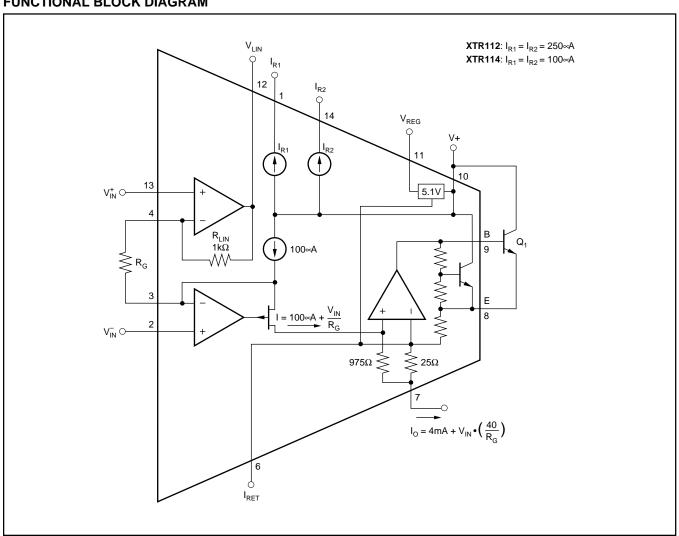
PRODUCT	CURRENT SOURCES	PACKAGE	PACKAGE DRAWING NUMBER ⁽¹⁾	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER ⁽²⁾	TRANSPORT MEDIA
XTR112U	2 x 250μA	SO-14 Surface Mount	235	-40°C to +85°C	XTR112U	Rails
"	"	"	"	"	XTR112U/2K5	Tape and Reel
XTR112UA	2 x 250μA	SO-14 Surface Mount	235	-40°C to +85°C	XTR112UA	Rails
"	"	"	"	"	XTR112UA/2K5	Tape and Reel
XTR114U	2 x 100μA	SO-14 Surface Mount	235	-40°C to +85°C	XTR114U	Rails
"	"	"	"	"	XTR114U/2K5	Tape and Reel
XTR114UA	2 x 100μA	SO-14 Surface Mount	235	-40°C to +85°C	XTR114UA	Rails
"	"	"	"	"	XTR114UA/2K5	Tape and Reel

NOTES: (1) For detailed drawing and dimension table, please see end of data sheet, or Appendix C of Burr-Brown IC Data Book. (2) Models with a slash (/) are available only in Tape and Reel in the quantities indicated (e.g., /2K5 indicates 2500 devices per reel). Ordering 2500 pieces of "XTR112UA/2K5" will get a single 2500-piece Tape and Reel. For detailed Tape and Reel mechanical information, refer to Appendix B of Burr-Brown IC Data Book.

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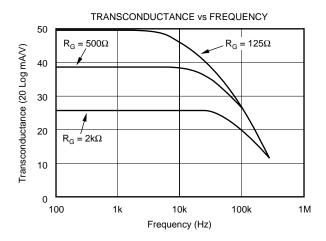


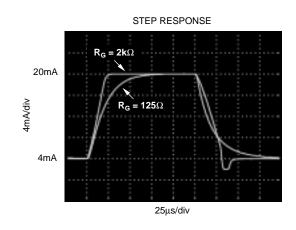
FUNCTIONAL BLOCK DIAGRAM

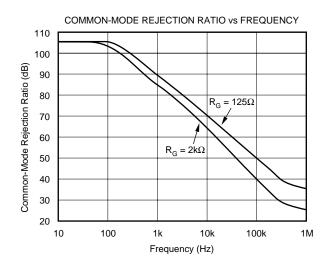


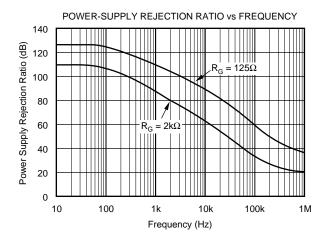
TYPICAL PERFORMANCE CURVES

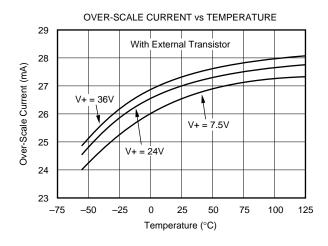
At $T_A = +25$ °C, and V+ = 24V, unless otherwise noted.

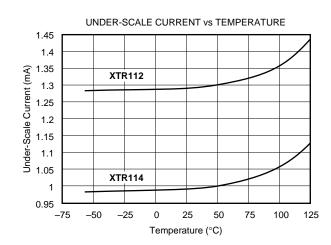






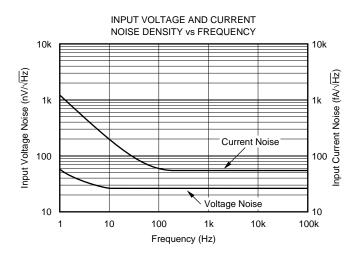


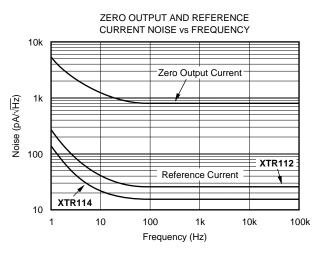


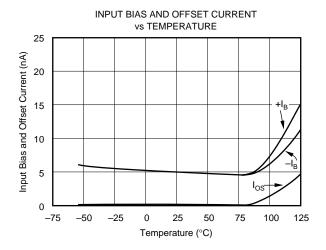


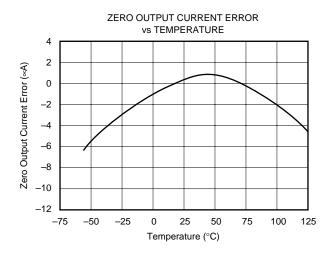
TYPICAL PERFORMANCE CURVES (CONT)

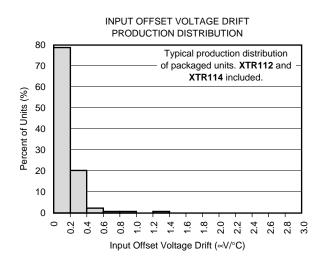
At $T_A = +25$ °C, and V+ = 24V, unless otherwise noted.

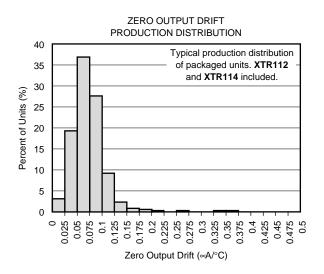






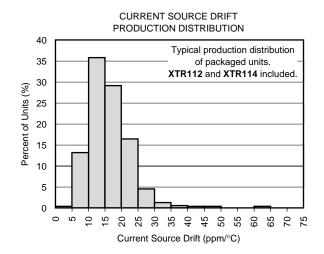


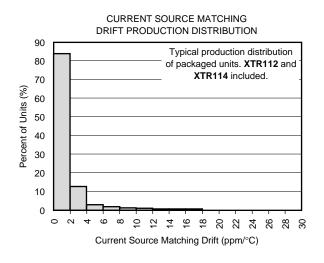


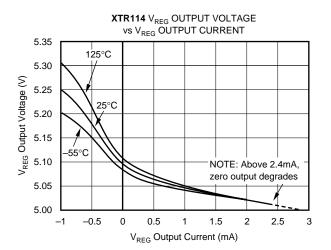


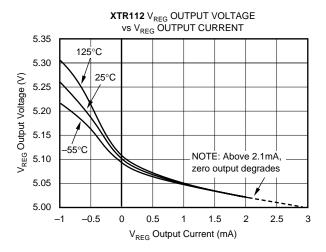
TYPICAL PERFORMANCE CURVES (CONT)

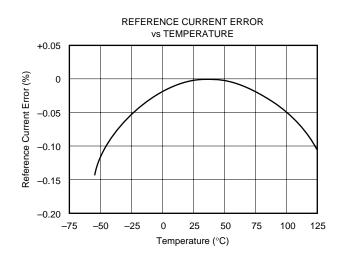
At $T_A = +25^{\circ}C$, and V+ = 24V, unless otherwise noted.











APPLICATION INFORMATION

Figure 1 shows the basic connection diagram for the XTR112 and XTR114. The loop power supply, V_{PS} , provides power for all circuitry. Output loop current is measured as a voltage across the series load resistor, $R_{\rm L}$.

Two matched current sources drive the RTD and zero-setting resistor, R_Z . These current sources are 250 μ A for the XTR112 and 100 μ A for the XTR114. Their instrumentation amplifier input measures the voltage difference between the RTD and R_Z . The value of R_Z is chosen to be equal to the resistance of the RTD at the low-scale (minimum) measurement temperature. R_Z can be adjusted to achieve 4mA output at the minimum measurement temperature to correct for input offset voltage and reference current mismatch of the XTR112 and XTR114.

 R_{CM} provides an additional voltage drop to bias the inputs of the XTR112 and XTR114 within their common-mode input range. R_{CM} should be bypassed with a $0.01\mu F$ capacitor to minimize common-mode noise. Resistor R_G sets the gain of the instrumentation amplifier according to the desired temperature range. R_{LIN1} provides second-order linearization correction to the RTD, typically achieving a 40:1 improvement in linearity. An additional resistor is required for three-wire RTD connections, see Figure 3.

The transfer function through the complete instrumentation amplifier and voltage-to-current converter is:

$$I_O = 4mA + V_{IN} \bullet (40/R_G)$$

(V_{IN} in volts, R_G in ohms)

where $V_{\rm IN}$ is the differential input voltage. As evident from the transfer function, if $R_{\rm G}$ is not used the gain is zero and the output is simply the XTR's zero current. The value of $R_{\rm G}$ varies slightly for two-wire RTD and three-wire RTD connections with linearization. $R_{\rm G}$ can be calculated from the equations given in Figure 1 (two-wire RTD connection) and Table I (three-wire RTD connection).

The I_{RET} pin is the return path for all current from the current sources and V_{REG} . The I_{RET} pin allows any current used in external circuitry to be sensed by the XTR112 and XTR114 and to be included in the output current without causing an error.

The V_{REG} pin provides an on-chip voltage source of approximately 5.1V and is suitable for powering external input circuitry (refer to Figure 6). It is a moderately accurate voltage reference—it is not the same reference used to set the precision current references. V_{REG} is capable of sourcing approximately 2.1mA of current for the XTR112 and 2.4mA for the XTR114. Exceeding these values may affect the 4mA zero output. Both products can sink approximately 1mA.

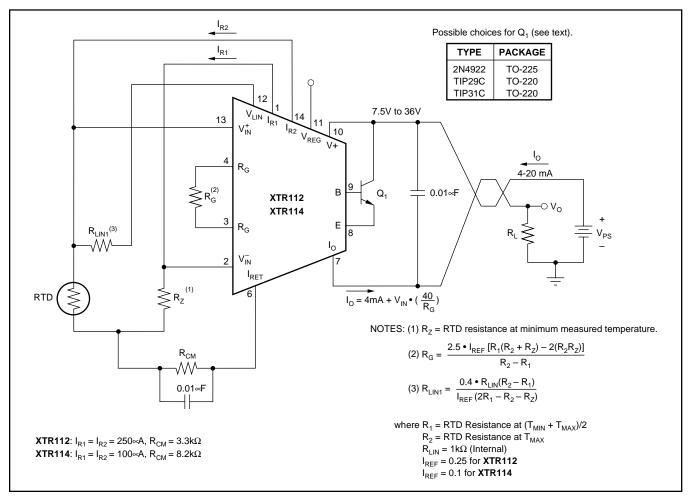


FIGURE 1. Basic Two-Wire RTD Temperature Measurement Circuit with Linearization.

A negative input voltage, $V_{\rm IN}$, will cause the output current to be less than 4mA. Increasingly negative $V_{\rm IN}$ will cause the output current to limit at approximately 1.3mA for the XTR112 and 1mA for the XTR114. Refer to the typical curve "Under-Scale Current vs Temperature."

Increasingly positive input voltage (greater than the full-scale input) will produce increasing output current according to the transfer function, up to the output current limit of approximately 27mA. Refer to the typical curve "Over-Scale Current vs Temperature."

EXTERNAL TRANSISTOR

Transistor Q_1 conducts the majority of the signal-dependent 4-20mA loop current. Using an external transistor isolates the majority of the power dissipation from the precision input and reference circuitry of the XTR112 and XTR114, maintaining excellent accuracy.

Since the external transistor is inside a feedback loop its characteristics are not critical. Requirements are: $V_{CEO} = 45V$ min, $\beta = 40$ min and $P_D = 800$ mW. Power dissipation requirements may be lower if the loop power supply voltage is less than 36V. Some possible choices for Q_1 are listed in Figure 1.

The XTR112 and XTR114 can be operated without this external transistor, however, accuracy will be somewhat degraded due to the internal power dissipation. Operation without Q_1 is not recommended for extended temperature ranges. A resistor ($R=3.3k\Omega$) connected between the I_{RET} pin and the E (emitter) pin may be needed for operation below 0°C without Q_1 to guarantee the full 20mA full-scale output, especially with V+ near 7.5V.

LOOP POWER SUPPLY

The voltage applied to the XTR112 and XTR114, V+, is measured with respect to the $I_{\rm O}$ connection, pin 7. V+ can

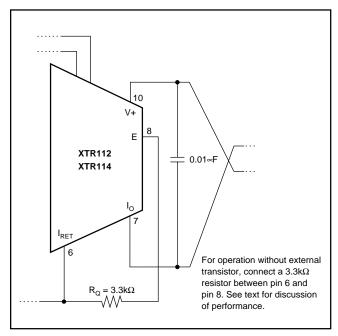


FIGURE 2. Operation Without External Transistor.

range from 7.5V to 36V. The loop supply voltage, V_{PS} , will differ from the applied voltage according to the voltage drop on the current sensing resistor, R_L (plus any other voltage drop in the line).

If a low loop supply voltage is used, R_L (including the loop wiring resistance) must be made a relatively low value to assure that V+ remains 7.5V or greater for the maximum loop current of 20mA:

$$R_{L} \max = \left(\frac{(V+) - 7.5V}{20 \text{ mA}}\right) - R_{WIRING}$$

It is recommended to design for V+ equal or greater than 7.5V with loop currents up to 30mA to allow for out-of-range input conditions.

The low operating voltage (7.5V) of the XTR112 and XTR114 allow operation directly from personal computer power supplies $(12V \pm 5\%)$. When used with the RCV420 Current Loop Receiver (Figure 7), load resistor voltage drop is limited to 3V.

ADJUSTING INITIAL ERRORS

Many applications require adjustment of initial errors. Input offset and reference current mismatch errors can be corrected by adjustment of the zero resistor, R_Z . Adjusting the gain-setting resistor, R_G , corrects any errors associated with gain.

TWO-WIRE AND THREE-WIRE RTD CONNECTIONS

In Figure 1, the RTD can be located remotely simply by extending the two connections to the RTD. With this remote two-wire connection to the RTD, line resistance will introduce error. This error can be partially corrected by adjusting the values of R_Z , R_G , and R_{LIN1} .

A better method for remotely located RTDs is the three-wire RTD connection shown in Figure 3. This circuit offers improved accuracy. R_Z 's current is routed through a third wire to the RTD. Assuming line resistance is equal in RTD lines 1 and 2, this produces a small common-mode voltage which is rejected by the XTR112 and XTR114. A second resistor, $R_{\rm LIN2}$, is required for linearization.

Note that although the two-wire and three-wire RTD connection circuits are very similar, the gain-setting resistor, $R_{\rm G}$, has slightly different equations:

Two-wire:
$$R_G = \frac{2.5 \bullet I_{REF} [R_1 (R_2 + R_Z) - 2 (R_2 R_Z)]}{R_2 - R_1}$$

Three-wire:
$$R_G = \frac{2.5 \bullet I_{REF}(R_2 - R_Z)(R_1 - R_Z)}{R_2 - R_1}$$

where $R_Z = RTD$ resistance at T_{MIN}

 $R_1 = RTD$ resistance at $(T_{MIN} + T_{MAX})/2$

 $R_2 = RTD$ resistance at T_{MAX}

 $I_{REF} = 0.25$ for XTR112 $I_{REF} = 0.1$ for XTR114



Table I summarizes the resistor equations for two-wire and three-wire RTD connections. An example calculation is also provided. To maintain good accuracy, at least 1% (or better) resistors should be used for $R_{\rm G}$. Table II provides standard 1% $R_{\rm G}$ values for a three-wire Pt1000 RTD connection with linearization for the XTR112. Table III gives $R_{\rm G}$ values for the XTR114.

LINEARIZATION

RTD temperature sensors are inherently (but predictably) nonlinear. With the addition of one or two external resistors, R_{LIN1} and R_{LIN2} , it is possible to compensate for most of this nonlinearity resulting in 40:1 improvement in linearity over the uncompensated output.

	TWO-WIRE		THREE-WIRE					
	R_{G}	R _{LIN1}	R_{G}	R _G R _{LIN1}				
General Equations	$= \frac{I_{REF} \cdot 2.5 \left[R_1 \left(R_2 + R_2 \right) - 2 \left(R_2 R_2 \right) \right]}{\left(R_2 - R_1 \right)}$	$= \frac{0.4 \cdot R_{LIN} (R_2 - R_1)}{I_{REF} \cdot (2R_1 - R_2 - R_2)}$	$= \frac{I_{REF} \cdot 2.5 (R_2 - R_Z) (R_1 - R_Z)]}{(R_2 - R_1)}$	$= \frac{0.4 \cdot R_{LIN} (R_2 - R_1)}{I_{REF} \cdot (2R_1 - R_2 - R_2)}$	$= \frac{0.4 \bullet (R_{LIN} + R_G)(R_2 - R_1)}{I_{REF} \bullet (2R_1 - R_2 - R_Z)}$			
XTR112 (I _{REF} = 0.25) (see Table II)	$= \frac{0.625 \cdot [R_1 (R_2 + R_2) - 2 (R_2 R_2)]}{(R_2 - R_1)}$	$= \frac{1.6 \cdot R_{LIN} (R_2 - R_1)}{(2R_1 - R_2 - R_2)}$	$= \frac{0.625 \cdot (R_2 - R_2) (R_1 - R_2)]}{(R_2 - R_1)}$	$= \frac{1.6 \cdot R_{LIN} (R_2 - R_1)}{(2R_1 - R_2 - R_2)}$	$= \frac{1.6 \bullet (R_{LIN} + R_G)(R_2 - R_1)}{(2R_1 - R_2 - R_Z)}$			
XTR114 (I _{REF} = 0.1) (see Table III)	$= \frac{0.25 \cdot [R_1 (R_2 + R_2) - 2 (R_2 R_2)]}{(R_2 - R_1)}$	$= \frac{4 \cdot R_{LIN} (R_2 - R_1)}{(2R_1 - R_2 - R_2)}$	$= \frac{0.25 \cdot (R_2 - R_2) (R_1 - R_2)]}{(R_2 - R_1)}$	$= \frac{4 \cdot R_{LIN} (R_2 - R_1)}{(2R_1 - R_2 - R_2)}$	$= \frac{4 \cdot (R_{LIN} + R_G)(R_2 - R_1)}{(2R_1 - R_2 - R_Z)}$			

where R_Z = RTD resistance at the minimum measured temperature, T_{MIN}

 R_1 = RTD resistance at the midpoint measured temperature, T_{MID} = $(T_{MIN} + T_{MAX})/2$

 R_2 = RTD resistance at maximum measured temperature, $T_{\rm MAX}$

 $R_{LIN} = 1k\Omega$ (internal)

XTR112 RESISTOR EXAMPLE:

The measurement range is -100° C to $+200^{\circ}$ C for a 3-wire Pt100 RTD connection. Determine the values for R_S, R_G, R_{LIN1}, and R_{LIN2}. Look up the values from the chart or calculate the values according to the equations provided.

METHOD 1: TABLE LOOK UP

 T_{MIN} = -100°C and ΔT = 300°C (T_{MAX} = +200°C), Using Table II the 1% values are:

 $\begin{aligned} R_Z &= 604\Omega & R_{LIN1} &= 33.2k\Omega \\ R_G &= 750\Omega & R_{LIN2} &= 59k\Omega \end{aligned}$

METHOD 2: CALCULATION

Step 1: Determine R_Z, R₁, and R₂.

 R_Z is the RTD resistance at the minimum measured temperature, $T_{MIN} = -100^{\circ}C$. Using Equation (1) at right gives $R_Z = 602.5\Omega$ (1% value is 604Ω).

 R_2 is the RTD resistance at the maximum measured temperature, T_{MAX} = 200°C. Using Equation (2) at right gives R_2 = 1758.4 Ω .

 $\ensuremath{R_{1}}$ is the RTD resistance at the midpoint measured temperature,

 $T_{MID}=(T_{MIN}+T_{MAX})/2=(-100+200)/2=50^{\circ}C.\ R_{1}$ is NOT the average of R_{Z} and R_{2} . Using Equation (2) at right gives $R_{1}=1194\Omega.$

Step 2: Calculate R_G , R_{LIN1} , and R_{LIN2} using equations above.

 $R_G = 757\Omega$ (1% value is 750Ω) $R_{LIN1} = 33.322k\Omega$ (1% value is $33.2k\Omega$) $R_{LIN2} = 58.548k\Omega$ (1% value is $59k\Omega$)

Calculation of Pt1000 Resistance Values

(according to DIN IEC 751)

Equation (1) Temperature range from -200°C to 0°C : $R_{(T)} = 1000 \ [1 + 3.90802 \bullet 10^{-3} \bullet T - 0.5802 \bullet 10^{-6} \bullet T^2 - 4.27350 \bullet 10^{-12} \bullet (T - 100) \bullet T^3]$

Equation (2) Temperature range from 0°C to +850°C: $R_{(T)} = 1000 \ (1 + 3.90802 \bullet 10^{-3} \bullet T - 0.5802 \bullet 10^{-6} \bullet T^2)$

where: $R_{(T)}$ is the resistance in Ω at temperature T. T is the temperature in ${}^{\circ}C$.

NOTE: Most RTD manufacturers provide reference tables for resistance values at various temperatures.

Resistor values for other RTD types (such as Pt2000) can be calculated using the XTR resistor selection program in the Applications Section on Burr-Brown's web site (www.burr-brown.com)

TABLE I. Summary of Resistor Equations for Two-Wire and Three-Wire Pt1000 RTD Connections.

MEASUREMENT TEMPERATURE SPAN AT (°C) 700°C T_{MIN} 100°C 200°C 300°C 400°C 500°C 600°C 800°C 900°C 1000°C 187/1050 187/1820 -200°C 187/267 187/536 187/806 187/1330 187/1580 187/2100 187/2370 187/2670 48700 9760 31600 25500 21500 17800 15000 13000 11300 8660 31600 61900 33200 48700 46400 44200 41200 39200 34800 36500 -100°C 604/255 604/499 604/4750 604/1000 604/1270 604/1500 604/1780 604/2050 604/2260 86600 49900 33200 24900 19600 15800 13300 11500 10000 110000 40200 37400 0°C 1000/243 1000/487 1000/732 1000/976 1000/1210 1000/1470 1000/1740 1000/1960 105000 51100 33200 24300 19100 15400 13000 11000 130000 76800 57600 48700 42200 38300 35700 33200 1370/715 1370/237 1370/475 1370/953 1370/1180 1370/1430 1370/1690 100°C R_{Z}/R_{G} 102000 49900 32400 23700 18700 15000 12400 56200 46400 127000 73200 40200 36500 33200

1740/1400

14300

34800

XTR112 1% RESISTOR VALUES FOR A THREE-WIRE RTD CONNECTION

200°C 1740/232 1740/464 1740/698 1740/931 1740/1150 100000 48700 31600 23200 17800 53600 121000 69800 44200 300°C 2100/221 2100/442 2100/665 2100/887 2100/1130 17400 95300 46400 30100 22100 118000 68100 51100 42200 36500 400°C 2490/215 2490/432 2490/649 2490/866 93100 45300 29400 21500 64900 48700 40200 113000 500°C 2800/210 2800/412 2800/619 887000 43200 28000

3160/402

42200

59000

45300

107000

3160/200

86600

102000

3480/191 82500

100000

3740/187

95300

600°C

700°C

800°C

NOTE: The values listed in the table are 1% resistors (in Ω). Exact values may be calculated from the following equations:

R_{LIN2} _

 R_7 = RTD resistance at minimum measured temperature, T_{MIN} .

$$\begin{split} R_G &= \frac{0.625 \bullet (R_2 - R_Z) (R_1 - R_Z)}{(R_2 - R_1)} \\ R_{LIN1} &= \frac{1.6 \bullet R_{LIN} (R_2 - R_1)}{(2R_1 - R_2 - R_Z)} \\ R_{LIN2} &= \frac{1.6 \bullet (R_{LIN} + R_G) (R_2 - R_1)}{(2R_1 - R_2 - R_Z)} \end{split}$$

where R_1 = RTD resistance at the midpoint measured temperature, $(T_{MIN} + T_{MAX})/2$

 R_2 = RTD resistance at T_{MAX}

 $R_{LIN} = 1k\Omega$ (Internal)

TABLE II. XTR112 R_Z, R_G, R_{LIN1}, and R_{LIN2} Standard 1% Resistor Values for Three-Wire Pt1000 RTD Connection with Linearization.

XTR114 1% RESISTOR VALUES FOR A THREE-WIRE RTD CONNECTION MEASUREMENT TEMPERATURE SPAN AT (°C) T_{MIN} 100°C 200°C 300°C 400°C 500°C 600°C 700°C 800°C 900°C 1000°C -200°C 187/107 187/215 187/316 187/422 187/523 187/634 187/732 187/845 187/953 187/1050 64900 121000 78700 53600 45300 38300 32400 28000 24900 21500 133000 95300 84500 76800 68100 68100 56200 52300 47500 45300 -100°C 604/102 604/200 604/301 604/402 604/511 604/604 604/715 604/806 604/909 221000 124000 84500 61900 48700 40200 33200 28700 24900 243000 150000 86600 63400 57600 47500 110000 0°C 1000/97.6 1000/196 1000/294 1000/392 1000/487 1000/590 1000/681 1000/787 261000 130000 39200 84500 61900 287000 154000 107000 84500 71500 61900 54900 49900 100°C 1370/95.3 1370/191 1370/287 1370/383 1370/475 1370/576 1370/665 124000 255000 80600 59000 46400 37400 31600 R_{Z}/R_{G} 68100 280000 147000 105000 82500 59000 52300 1740/90.9 1740/182 200°C 1740/274 1740/365 1740/464 1740/549 R_{LIN2} 249000 121000 78700 57600 44200 36500 267000 143000 100000 78700 64900 300°C 2100/88.9 2100/178 2100/267 2100/357 2100/348 237000 NOTE: The values listed in the table are 1% resistors (in Ω). 261000 137000 95300 75000 61900 Exact values may be calculated from the following equations: 400°C 2490/86.6 2490/174 2490/261 2490/249 113000 R_Z = RTD resistance at minimum measured temperature, T_{MIN} 232000 73200 53600 249000 71500 133000 93100 2800/82.5 2800/165 500°C 2800/49 $R_{G} = \frac{0.25 \bullet (R_{2} - R_{Z}) (R_{1} - R_{Z})}{(R_{2} - R_{1})}$ 110000 221000 69800 243000 127000 88700 $\mathsf{R}_{\mathsf{LIN1}} = \frac{4 \bullet \mathsf{R}_{\mathsf{LIN}} (\mathsf{R}_2 - \mathsf{R}_1)}{(2\mathsf{R}_1 - \mathsf{R}_2 - \mathsf{R}_Z)}$ 600°C 3160/80.6 3160/162 215000 215000 121000 $\mathsf{R}_{\mathsf{LIN2}} = \frac{4 \bullet (\mathsf{R}_{\mathsf{LIN}} + \mathsf{R}_{\mathsf{G}}) \, (\mathsf{R}_2 - \mathsf{R}_1)}{(2\mathsf{R}_1 - \mathsf{R}_2 - \mathsf{R}_{\mathsf{Z}})}$ 700°C 3480/76.8 205000 221000 where R_1 = RTD resistance at the midpoint measured temperature, $(T_{MIN} + T_{MAX})/2$ 800°C 3740/75 $R_2 = RTD$ resistance at T_{MAX} 200000 215000 $R_{LIN} = 1k\Omega$ (Internal)

TABLE III. XTR114 R_Z, R_G, R_{LIN1}, and R_{LIN2} Standard 1% Resistor Values for Three-Wire Pt1000 RTD Connection with Linearization.

A typical two-wire RTD application with linearization is shown in Figure 1. Resistor R_{LIN1} provides positive feedback and controls linearity correction. R_{LIN1} is chosen according to the desired temperature range. An equation is given in Figure 1.

In three-wire RTD connections, an additional resistor, R_{LIN2} , is required. As with the two-wire RTD application, R_{LIN1} provides positive feedback for linearization. R_{LIN2} provides an offset canceling current to compensate for wiring resistance encountered in remotely located RTDs. R_{LIN1} and R_{LIN2} are chosen such that their currents are equal. This makes the voltage drop in the wiring resistance to the RTD a common-mode signal which is rejected by the XTR112 and XTR114. The nearest standard 1% resistor values for R_{LIN1} and R_{LIN2} should be adequate for most applications. Tables II and III provide the 1% resistor values for a three-wire Pt1000 RTD connection.

If no linearity correction is desired, the V_{LIN} pin should be left open. With no linearization, $R_G = 2500 \cdot V_{FS}$, where $V_{FS} =$ full-scale input range.

RTDs

The text and figures thus far have assumed a Pt1000 RTD. With higher resistance RTDs, the temperature range and input voltage variation should be evaluated to ensure proper common-mode biasing of the inputs. As mentioned earlier,

 R_{CM} can be adjusted to provide an additional voltage drop to bias the inputs of the XTR112 and XTR114 within their common-mode input range.

ERROR ANALYSIS

Table IV shows how to calculate the effect various error sources have on circuit accuracy. A sample error calculation for a typical RTD measurement circuit (Pt1000 RTD, 200°C measurement span) is provided. The results reveal the XTR112's and XTR114's excellent accuracy, in this case 1% unadjusted for the XTR112, 1.16% for the XTR114. Adjusting resistors $R_{\rm G}$ and $R_{\rm Z}$ for gain and offset errors improves the XTR112's accuracy to 0.28% (0.31% for the XTR114). Note that these are worst-case errors; guaranteed maximum values were used in the calculations and all errors were assumed to be positive (additive). The XTR112 and XTR114 achieve performance which is difficult to obtain with discrete circuitry and requires less space.

OPEN-CIRCUIT PROTECTION

The optional transistor Q_2 in Figure 3 provides predictable behavior with open-circuit RTD connections. It assures that if any one of the three RTD connections is broken, the XTR's output current will go to either its high current limit ($\approx 27\text{mA}$) or low current limit ($\approx 1.3\text{mA}$ for XTR112 and $\approx 1\text{mA}$ for XTR114). This is easily detected as an out-of-range condition.

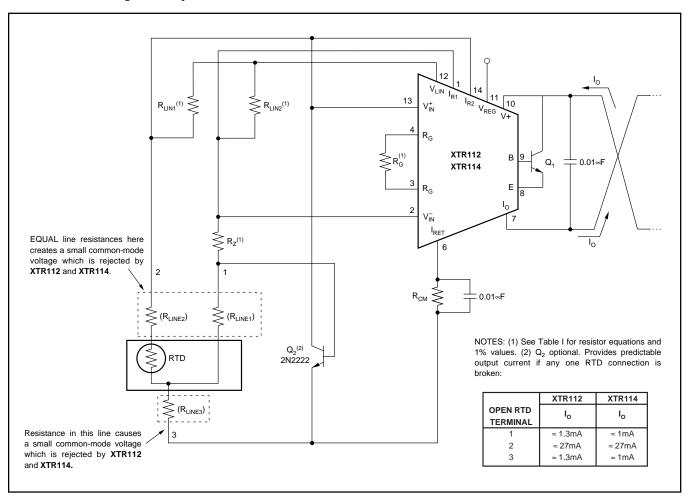


FIGURE 3. Three-Wire Connection for Remotely Located RTDs.

SAMPLE ERROR CALCULATION FOR XTR112(1)

RTD value at 4mA Output ($R_{RTD\,MIN}$) 1000 Ω RTD Measurement Range 200°C Ambient Temperature Range (ΔT_A) 20°C Supply Voltage Change ($\Delta V+$) 5V Common-Mode Voltage Change (ΔCM) 0.1V

			ROR Full Scale)	
ERROR SOURCE	ERROR EQUATION	SAMPLE ERROR CALCULATION ⁽²⁾	UNADJ.	ADJUST.
INPUT Input Offset Voltage vs Common-Mode Input Bias Current Input Offset Current	V _{OS} /(V _{IN MAX}) • 10 ⁶ CMRR • ∆CM/(V _{IN MAX}) • 10 ⁶ I _B /I _{REF} • 10 ⁶ I _{OS} • R _{RTD MIN} /(V _{IN MAX}) • 10 ⁶	100μV/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 50μV/V • 0.1V/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 0.025μA/250μA • 10 ⁶ 3nA • 1000Ω/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ Total Input Error:	526 26 100 16 668	0 26 0 0
EXCITATION Current Reference Accuracy vs Supply Current Reference Matching vs Supply	I _{REF} Accuracy (%)/100% • 10 ⁶ (I _{REF} vs V+) • ΔV+ I _{REF} Matching (%)/100% • I _{REF} • R _{RTD MIN} /(V _{IN MAX}) • 10 ⁶ (I _{REF} matching vs V+) • ΔV+ • R _{RTD MIN} /(V _{IN MAX})	0.2%/100% • 10 ⁶ 25ppm/V • 5V 0.1%/100% • 250μA • 1000Ω/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 10ppm/V • 5V • 250μA • 1000Ω/(250μA • 3.8Ω/°C • 200°C) Total Excitation Error:	2000 125 1316 66 3507	0 125 0 66 191
GAIN Span Nonlinearity	Span Error (%)/100% • 10 ⁶ Nonlinearity (%)/100% • 10 ⁶	0.2%/100% • 10 ⁶ 0.01%/100% • 10 ⁶ Total Gain Error:	2000 100 2100	0 100 100
OUTPUT Zero Output vs Supply	(I _{ZERO} - 4mA)/16000μA • 10 ⁶ (I _{ZERO} vs V+) • ΔV+/16000μA • 10 ⁶	25μΑ/16000μΑ • 10 ⁶ 0.2μΑ/V • 5V/16000μΑ • 10 ⁶ Total Output Error :	1563 63 1626	0 63 63
DRIFT (ΔT _A = 20°C) Input Offset Voltage Input Bias Current (typical) Input Offset Current (typical) Current Reference Accuracy Current Reference Matching Span Zero Output	$\begin{array}{c} \text{Drift} \bullet \Delta T_A/(V_{\text{IN MAX}}) \bullet 10^6 \\ \text{Drift} \bullet \Delta T_A/R_{\text{RF}} \bullet 10^6 \\ \text{Drift} \bullet \Delta T_A \bullet R_{\text{RTD MIN}}/(V_{\text{IN MAX}}) \bullet 10^6 \\ \text{Drift} \bullet \Delta T_A \bullet R_{\text{RTD MIN}}/(V_{\text{IN MAX}}) \bullet 10^6 \\ \text{Drift} \bullet \Delta T_A \bullet I_{\text{RFF}} \bullet R_{\text{RTD MIN}}/(V_{\text{IN MAX}}) \\ \text{Drift} \bullet \Delta T_A \bullet I_{\text{AFF}} \bullet \Delta T_A \\ \text{Drift} \bullet \Delta T_A/16000 \mu \text{A} \bullet 10^6 \\ \end{array}$	1.5μV/°C • 20°C/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 20pA/°C • 20°C/250μA • 10 ⁶ 5pA/°C • 20°C • 1000Ω/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 35ppm/°C • 20°C 15ppm/°C • 20°C • 250μA • 1000Ω/(250μA • 3.8Ω/°C • 200°C) 25ppm/°C • 20°C 0.5μA/°C • 20°C/16000μA • 10 ⁶ Total Drift Error:	158 2 0.5 700 395 500 626 2382	158 2 0.5 700 395 500 626 2382
NOISE (0.1Hz to 10Hz, typ) Input Offset Voltage Current Reference Zero Output	v _n /(V _{IN MAX}) • 10 ⁶ I _{REF} Noise • R _{RTD MIN} (V _{IN MAX}) • 10 ⁶ I _{ZERO} Noise/16000μA • 10 ⁶	0.6μV/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 3nA • 1000Ω/(250μA • 3.8Ω/°C • 200°C) • 10 ⁶ 0.03μA/16000μA • 10 ⁶ Total Noise Error:	3 16 2 21	3 16 2 21
		TOTAL ERROR:	10304	2783

NOTES: (1) For XTR114, $I_{REF} = 100\mu A$. Total unadjusted error is 1.16%, adjusted error 0.31%. (2) All errors are min/max and referred to input, unless otherwise stated.

TABLE IV. Error Calculation.

REVERSE-VOLTAGE PROTECTION

The XTR112's and XTR114's low compliance rating (7.5V) permits the use of various voltage protection methods without compromising operating range. Figure 4 shows a diode bridge circuit which allows normal operation even when the voltage connection lines are reversed. The bridge causes a two diode drop (approximately 1.4V) loss in loop supply voltage. This results in a compliance voltage of approximately 9V—satisfactory for most applications. If 1.4V drop in loop supply is too much, a diode can be inserted in series with the loop supply voltage and the V+ pin. This protects against reverse output connection lines with only a 0.7V loss in loop supply voltage.

SURGE PROTECTION

Remote connections to current transmitters can sometimes be subjected to voltage surges. It is prudent to limit the maximum surge voltage applied to the XTR to as low as practical. Various zener diode and surge clamping diodes are specially designed for this purpose. Select a clamp diode with as low a voltage rating as possible for best protection. For example, a 36V protection diode will assure proper transmitter operation at normal loop voltages, yet will provide an appropriate level of protection against voltage surges. Characterization tests on three production lots showed no damage to the XTR112 or XTR114 within loop supply voltages up to 65V.

(1.03%)

(0.28%)



Most surge protection zener diodes have a diode characteristic in the forward direction that will conduct excessive current, possibly damaging receiving-side circuitry if the loop connections are reversed. If a surge protection diode is used, a series diode or diode bridge should be used for protection against reversed connections.

RADIO FREQUENCY INTERFERENCE

The long wire lengths of current loops invite radio frequency interference. RF can be rectified by the sensitive input circuitry of the XTR112 and XTR114 causing errors. This generally appears as an unstable output current that varies with the position of loop supply or input wiring.

If the RTD sensor is remotely located, the interference may enter at the input terminals. For integrated transmitter assemblies with short connection to the sensor, the interference more likely comes from the current loop connections.

Bypass capacitors on the input reduce or eliminate this input interference. Connect these bypass capacitors to the I_{RET} terminal as shown in Figure 5. Although the dc voltage at the I_{RET} terminal is not equal to 0V (at the loop supply, V_{PS}) this circuit point can be considered the transmitter's "ground." The $0.01\mu F$ capacitor connected between V+ and I_O may help minimize output interference.

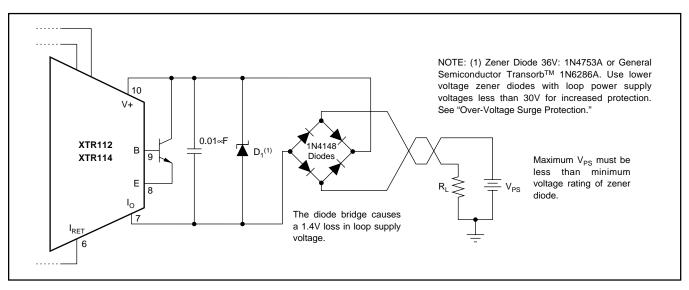


FIGURE 4. Reverse Voltage Operation and Over-Voltage Surge Protection.

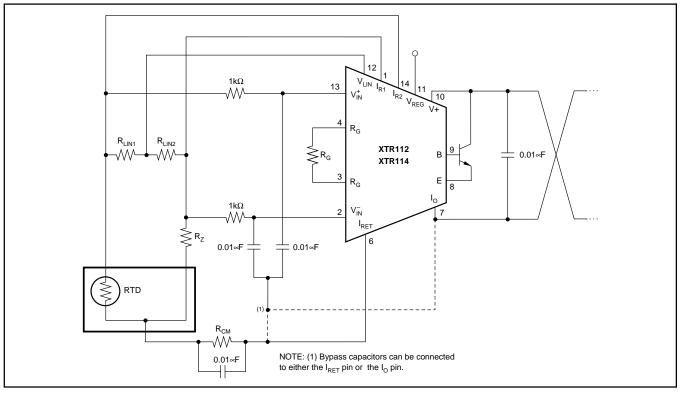


FIGURE 5. Input Bypassing Technique with Linearization.

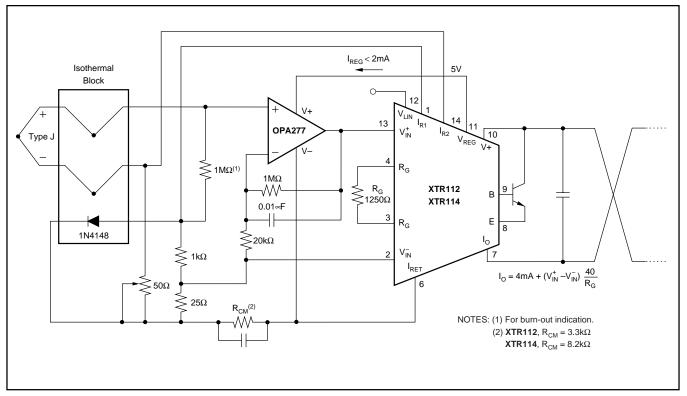


FIGURE 6. Thermocouple Low Offset, Low Drift Loop Measurement with Diode Cold-Junction Compensation.

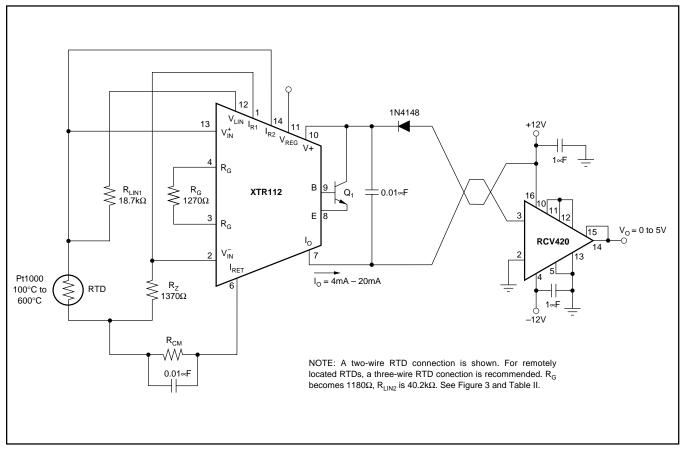


FIGURE 7. ±12V Powered Transmitter/Receiver Loop.

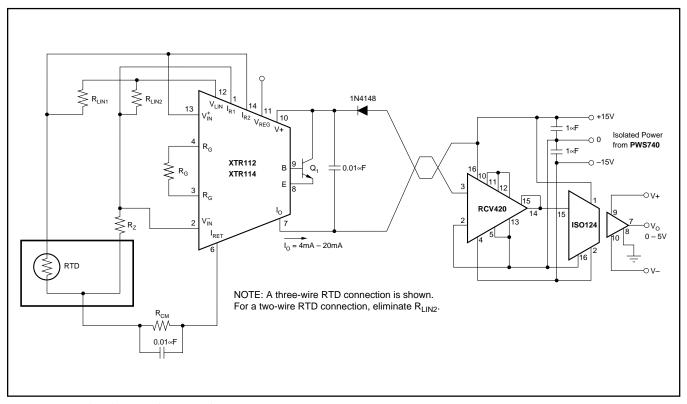


FIGURE 8. Isolated Transmitter/Receiver Loop.

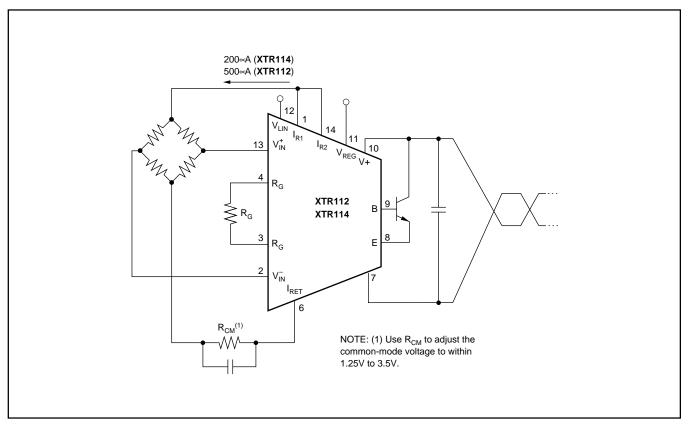


FIGURE 9. Bridge Input, Current Excitation.

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
XTR112U	ACTIVE	SOIC	D	14	50	RoHS & Green	Call TI	Level-3-260C-168 HR		XTR112U	Samples
XTR112UA	ACTIVE	SOIC	D	14	50	RoHS & Green	Call TI	Level-3-260C-168 HR	-40 to 85	XTR112U A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
XTR112U	D	SOIC	14	50	506.6	8	3940	4.32
XTR112UA	D	SOIC	14	50	506.6	8	3940	4.32

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